



Business Outlook for the NVM Market

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Nonvolatile Flash memory activity - markets

- 2005: \$20.5 billion
- 2010: \$51.8 billion
- CAGR: 20.4%

Nonvolatile memory activity – S&T and R&D

- 30+ technologies and technology variations

Content

- Summary
- New Market Segmentation
- Mobility Segment
- Non-Volatile Memory Market Forecast
- Conclusions

Web-Feet Research - Introduction

• Web-Feet Research:

Web: connects the world wide web or internet Feet: provides direction

- Vision:
 - qualitatively and quantitatively define the Non Volatile Memory and Storage markets strategy
- Charter:
 - bridge or translate the concepts of the Non Volatile Memory and Storage technologies from research and development into component manufacturing
 - implementing these components into memory sub-systems
 - quantifying the market applications usage and its impact on the financial markets

Summary

- INFLECTION POINT drivers: markets, applications
 - Changing market structure
 - New market segmentation
 - New use models for electronic devices
 - More demanding system requirements
 - Managing growth in Storage (NAND) market
 - Need for rejuvenating Memory (NOR) market
- INFLECTION POINT implications: storage
 - 1. Linear increase in DEMAND for Memory cards, MCP / SiP, EFD, Solid state drives (SSD)
 - 2. Geometric increase in Capacity: components and bytes
 - 3. Increase in access performance and security
 - 4. Need for a flexible memory business structure

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Market Changes – Function Model Evolution



• Old function model market segmentation

3C

- Computers and Peripherals PC, printers, Notebooks, HDD
- Communications Cell phones, modems, pagers, STB, Networking
- Consumer Digital cameras, MP3, Games, TV, camcorders
- Industrial Meters, sensors, medical, POS, industrial controllers
- Transportation Automotive, GPS
- Government Avionics, Guidance, Field Computers, ID tags

Market Changes – Use Model Evolution



- New use model segmentation
 - STATIONARY device cannot be easily moved
 - Mains powered
 - Wired connectivity
 - Examples: desk top PC, STB
 - PORTABILITY device can be easily moved, but nor worn by user
 - Battery powered
 - <u>Wired</u>/wireless connectivity
 - Examples: notebook, game consoles
 - MOBILITY device can be worn by user
 - Battery powered
 - Wireless connectivity
 - Very small form factor
 - Examples: cell phones, mobile terminals

Market Changes – Device Functionality Evolution



- Transition
 - From: MARKET FUNCTION-based segmentation
 - To: USE-MODEL-based segmentation
 - To: USE-FUNCTION-based converged segmentation
- MOBILITY
 - Drives the INFLECTION POINT for NV memories
- STATIONARY / PORTABILITY
 - Evolutionary, highly predictable
 - Changes in Computing memory subsystems, generates new inflection point

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Memory Hierarchies – General Computing Evolution

Performance



• Memory Hierarchy Evolution:

Registers:	 Volatile: flip flops - no functional change
L1 cache:	 Volatile: SRAM - no functional change
L2 cache :	 Volatile: SRAM no change, may add L3 cache
Work Memory:	 Volatile: DRAM – PC-based system
	 Non-Volatile: NOR – XIP for PC-based system
Storage: New segment	 Non-Volatile: NAND – Personal storage > Mass storage Non-Volatile: HDD/Optical – Personal < Mass storage

Mobility – System Architecture



- The MOBILITY segment begins to mature
 - In the '90s: dedicated MPU/MCU specifications
 - In the '00s: dedicated memory/storage components
- Fusion computing the mobility architecture
- Fusion computing impact on system memory
 - <u>System memory</u> split into:
 - 1. Work memory: XIP
 - 2. Storage Personal
 - Many more key functions

Mobility Memory – Evolution



- WORK MEMORY vs. STORAGE
 - Capacity increase pace

.

- WORK MEMORY Approx. 10% p.a. → x 2 by 2010
- STORAGE Approx. X 3 p.a. → x 2,000 by 2010
- Performance increase drivers
 - WORK MEMORY CPU performance driven
 - STORAGE Market / applications driven

Mobility Market – Functionality Evolution



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Mobility Market – Storage Performance Requirements 1

- Key performance driver:
 - Video (high definition) will migrate into the MOBILITY space the same way audio did
 - Time frame 2005 -2010
 - Preparations
 - MPEG 7 / MPEG 21 specifications
 - UDF specification to be replace by FAT (File Allocation Table) file format for local audio/video storage in computers (including MOBILE)

Trend 1: need for higher storage capacity

- Capacities
 - Up to 50GB (the new DVD standard for HDTV recording/playback)
- Forecast maximum capacity for memory cards (market driven):
 - Maximum capacity CAGR: 42%

GB Memory cards – maximum capacities:



Mobility Market – Storage Performance Requirements 2

Trend 2: need for higher storage performance

- Write performance
 - 80Mbps (system level); corresponds to approx. 20MBps on component level
- Read performance
 - 80Mbps (system level); corresponds to approx. 20MBps on component level
- Symmetrical read and write performance

Market defined performance classes:

	Description	Pixel resolution	Colors	Frame speed	Bit rate
Clip	Picture clips	4 Mp-16 Mp	3x8		
Clip-mot	Clip motion	4 Mp-16 Mp	3x8	8 fps	24 kbps
NB-Im	Narrow band imaging	VGA-XGA	1x8	15 fps	24-64 kbps
BB-Im	Broad band imaging	VGA-SXGA	2x8	15 fps	0.25-18 Mbps
NB-V/A	Narrow band video/audio	VGA-SVGA	2x8	30 fps	24-64 kbps
BB-V/A	Broad band video/audio	VGA-SVGA	3x8	30 fps	0.25-18 Mbps
Db/c-V/A	Digital broadcast video/audio	UXGA (HDTV)	3x8	30 fps	80 Mbps
Data	Computer files				highest available

Trend 3: increased need security features

Trend 4: linearly increasing demand for mobile storage



Business Outlook NVM Market

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New Application - Hybrid Flash or Robson

- 1. Hybrid Flash/Robson Benefits:
 - Positioned between DRAM and HDD in Vista O/S
 - Faster Bootup 3x faster
 - Fast Resume 14sec vs 17sec
 - Application Acceleration Super Fetch = 3x launch improvement
 - Power Reduction 1 of 10 hits spin HDD
 - 9% more battery life = 30 min.
 - Reliability improvements = MTBF increases
 - Target Markets
 - Laptop PC battery life, various HDD RPM speeds
 - Extreme Gamer PCs performance is everything

2. Hybrid Flash:

- NAND component densities: 512Mbit, 1Gbit, 2Gbit
- Built into HDD BOM
- Possible HDD RPM speed enhancement
- 3. Robson Flash:
 - PCI Express bus mini-module densities: 128MB, 256MB, 512MB, 1GB, 2GB, 4GB
 - Added as after-market Flash module
 - No impact on HDD BOM
 - More density = more acceleration
 - Possible upgrade configuration to existing Hybrid Flash in HDD

Memory Hierarchy – Mobile Storage

1. Mobile Personal Storage:

- Personal preferences layer added to system
 - Firmware U3 USB Smart Drives
 - Software additional function in Vista O/S from Microsoft,
 - NomaDrive better than U3
- Personalization and Security
 - Captures desktop settings, email, application programs, personal data files
 - Provides enhanced security, authentication, ecommerce, DRM

2. Mobile Mass Storage:

- Blank Media stores data in generic sense
- Memory Cards: SD, MMC, CF, MS, xD, USB Drives, MegaSIM
- Solid State Drives: Flash-based (NAND) Silicon Drive
 - Interfaces to system like HDD

Flash Cards – Form Factors



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Storage Market Segmentation – By Capacity



Storage Market Dynamics 1



- New battle ground the mobility space
- Mobility storage market trends
 - Fastest growing (CAGR ~16% over 10 years)
 - Attempts to penetrate this space by
 - 1. Solid State Storage (higher density / lower cost)
 - 2. HDD Storage (smaller form factors)
 - 3. New technologies (2 known so far)

Storage Market Dynamics 2



HDD strategy

Create smaller form factors

Semiconductor strategy

- Keep form factor
- Increase volumetric density

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Flash Memory Market Overview

- 2005 Flash memory revenues \$20.5 billion
 - 2006 Flash memory revenues expands to \$25.1 billion
- 2005 Flash memory units grew 42% in 2005 to 5 billion
 - Main unit growth driver double digit growth rates for applications
 - 6.6 billion in 2006
- NAND production
 - 2H of 2005 production slightly below demand
 - 2006 production higher than demand for overall year, end only 0.5% over
- NOR production
 - High density NOR increasing density, sluggish production capacity
 - Low density NOR teetering with oversupply, growing demand

Flash Revenue, Units and ASP Forecast



- Revenue and units demand growing linearly thru 2010
- Aggregate ASPs decline in 2005, excess NAND and financial markets force down prices
- Product mix shifts to higher ratio of high density and high priced parts, raises aggregate ASPs thru 2010

Flash Revenue Forecast



- NOR revenue mild growth until 2005, demand is offset by price declines, revenues reflect slight growth thru 2010
- NAND has accelerated high growth thru 2010, shipment volume much higher than annual price declines
- NAND demand stimulated by Mobile storage: Digital Still Camera, USB Flash Drives, MP3, and TV/Video recording in 2006 and beyond

Flash TeraByte Demand Forecast



- Memory NOR TeraByte growth 47.4% CAGR, only one tenth of NAND by 2005, 3% 2010
- Storage NAND TB growth 122.9% CAGR, doubles through 2010

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Revenue Forecast by All Mobile Non-Volatile Architectures

- NAND includes Floating Gate, Trapped Charge
- NOR includes FG, Trapped Charge
- emFlash embedded Flash monolithically integrated within same die with logic
- alternative NVM FRAM, MRAM, CRAM, PFRAM, nanoRAM, RRAM, Probe Memories, PIRAM
- microHDD 1" or .85" Hard Disk Drives for Mobile market (system ASP instead of component)

Summary – NAND Flash Market Vendors 1

- Samsung generated highest sales of NAND
 - Expand memory production with MLC 8Gbit by May 2006
 - Shipping OneNAND in wireless and addressing embedded NOR markets
 - Announced Hybrid Flash Drive and Solid State Drives for laptop 2007-2008
 - Increasing density from 1GB to 2GB for MMC micro
 - Major influence on market demand and production
- Toshiba produced NAND in second place in 2005 for all Flash
 - Flash Alliance JV manufacturing with SanDisk
 - Ramping fab 3 production, announce fab 4 and fab 5 build
 - Production 70nm 4Gbit NAND SLC and 8Gbit MLC NAND
 - Promotes: 300mm Fab, MLC NAND, SD card form factors
- Hynix/STMicro shipping NAND, follows Samsung roadmap
 - 512Mbit 4Gbit NAND, MLC Q2 2006, MCP NAND
 - No pricing relief in 2006 with oversupply
 - Fastest NAND read speed 36MB/sec
- Renesas retiring from all Flash memory production
 - Released 4Gbit Q4 2004, cancelled 8Gbit development
 - Possible licensing all AG-AND to PSC

Summary – NAND Flash Market Vendors 2

- Qimonda (formerly Infineon) shipping Flash cards only
 - TwinNAND NROM-type (512Mbit and 1Gbit components) Flash, 1.8V/3V version
 - 2-4Gbit product in 2007, as QuadBit line comes on-line
 - IPO for Qimonda Summer 2006
- Micron shipping 1-4Gbit NAND
 - Shipped 4Gbit NAND in Q4 2005
 - Purchased Lexar Media merging two cultures
- IM Flash Technologies Intel & Micron formed alliance to develop and manufacture NAND
 - JV develops and manufacture NAND: Boise 06, Manassas 2H 06, Lehi 07
 - 1, 2, 4Gbit SLC now, MLC in first phase development
- SanDisk Flash Alliance joint production of NAND with Toshiba, Retail, IP businesses
 - Fab 4 announced for Q4 2007
 - Purchase of msystems
 - Product diversification
 - All Flash card form factors
 - U3 and USB Drives
 - MP3 Player
 - iNAND stacked MCP EFD (Embedded Flash Drive)
- Saifun/SMIC joint venture/foundry relationship
 - Scheduled to produce 2-bit and 4-bit QuadBit NROM 2006
 - Producing emFlash along with components

Summary – NOR Flash Market Vendors 1

- Intel regained first place in NOR 2005
 - Making most in saturated NOR market
 - Ramping StrataFlash for cellular, (embedded) market
 - Introduced 1Gbit Flash at 65nm production
 - Expand market share:
 - Attack 128M-1G NAND with lower cost NOR
 - Release 16M-128M NOR with SPI and lower cost
- Spansion regained first place in NOR 1H 2006
 - IPO spun off Spansion as separate company December 2005
 - Expand MirrorBit product line: SPI, ORNAND 1Gbit, QuadBit
 - Established foundry relationship with TSMC
- STMicro NOR sales growth in declining price market
 - Considering memory division fate: Spin-off, merge, or make profitable
 - Developed MCP MLC NOR partnership with Intel, second source and standards
 - Introduced new line of MLC NOR products
 - Increasing serial Flash and FWH/LPC shipments
- Sharp NOR sales to fourth place
 - Rumored to exit NOR Flash market

Summary – NOR Flash Market Vendors 2

- Samsung generated MCP NOR
 - Developed NOR 32-256M products for MCP
 - Fab 6 will run EOL for MCP NOR then discontinue by 2008
- Toshiba respectable MCP NOR shipments
 - Offsetting NOR MCP volumes with NAND MCP offerings in 2006
- Renesas produced NOR
 - Maintaining market for Combo/MCP wireless sales
- SST shipped NOR
 - Continuing to expand presence in low end of NOR market
 - Diversify to non-NOR peripherals and controllers
- Macronix shipping higher volumes of NOR
 - Developing NROM-type high capacity product with Saifun long term
 - Nbit NROM NOR-type MirrorBit compatible product line released then sued

Flash Components Market Shares

Rank			Flash Vendor	\$ in Millions			%	Market Share %		
23	24	25		2003	2004	2005	Change	2004	2005	Change
1	1	1	Samsung	2952.0	4896.7	7015.0	43.3%	28.2%	34.2%	6.0
2	4	2	Toshiba	1912.0	2067.1	2569.6	24.3%	11.9%	12.5%	0.6
4	3	3	Intel	1673.7	2349.1	2295.0	(2.3%)	13.5%	11.2%	(2.3)
3	2	4	Spansion	1740.0	2411.3	2045.0	(15.2%)	13.9%	10.0%	(3.9)
23	11	5	Hynix	6.0	315.2	1551.0	392.1%	1.8%	7.6%	5.7
7	5	6	STMicroelectronics	783.0	1196.0	1321.0	10.5%	6.9%	6.4%	(0.4)
8	7	7	SanDisk	401.0	836.1	908.0	8.6%	4.8%	4.4%	(0.4)
5	6	8	Renesas	1040.0	864.6	651.0	(24.7%)	5.0%	3.2%	(1.8)
6	8	9	Sharp	819.0	801.0	522.0	(34.8%)	4.6%	2.5%	(2.1)
9	10	10	SST	249.0	346.6	363.0	4.7%	2.0%	1.8%	(0.2)
13	13	11	Micron	64.0	179.3	320.0	78.5%	1.0%	1.6%	0.5
10	9	12	Macronix	224.8	393.4	214.0	(45.6%)	2.3%	1.0%	(1.2)
NR	NR	13	M-Systems	n/a	73.2	194.5	165.7%	0.4%	0.9%	0.5
12	12	14	Atmel	150.9	192.0	157.0	(18.2%)	1.1%	0.8%	(0.3)
NR	15	15	Infineon	0.0	84.1	152.0	80.7%	0.5%	0.7%	0.3
11	14	16	NEC	203.0	151.3	71.0	(53.1%)	0.9%	0.3%	(0.5)
15	17	17	PMC	41.1	44.4	42.0	(5.4%)	0.3%	0.2%	(0.1)
14	16	18	Winbond	57.1	54.4	40.0	(26.5%)	0.3%	0.2%	(0.1)
17	22	NR	NexFlash	12.0	12.0	n/a	n/a	0.1%	n/a	n/a
22	21	19	EON	7.0	17.0	14.2	(16.5%)	0.1%	0.1%	(0.0)
21	19	20	AMIC	8.0	22.0	13.0	(40.9%)	0.1%	0.1%	(0.1)
16	18	21	Sanyo	25.0	25.0	12.0	(52.0%)	0.1%	0.1%	(0.1)
19	24	22	Matsushita	10.0	7.0	12.0	71.4%	0.0%	0.1%	0.0
18	23	23	Mosel Vitelic	10.0	8.0	9.0	12.5%	0.0%	0.0%	(0.0)
24	25	24	Catalyst	5.7	6.1	5.2	(14.8%)	0.0%	0.0%	(0.0)
25	26	25	IMT	5.0	5.0	5.0	n/a	0.0%	0.0%	(0.0)
NR	27	26	Excel	n/a	2.4	2.4	n/a	n/a	0.0%	n/a
20	20	27	Tower	9.0	18.0	0.0	n/a	0.1%	0.0%	(0.1)
27	28	28	Others	10.0	5.0	9.0	80.0%	n/a	0.0%	n/a
			Total	\$12,418	\$17,383	\$20,513	18.0%	100%	118%	n/a
		13.75								

*NR= Not Ranked

Source: Web-Feet Research

Business Models – Storage/Memory Hardware Diversification

Develop various storage/memory subsystems

- Flash silicon components 1-bit per cell, 2-bit per cell
 - NOR, NAND, TC, Alternative
- Embedded silicon memory 1-bit per cell, 2-bit per cell
 - NOR, TC, Alternative
- Embedded Flash Drive component + controller
 - MDOC, OneNAND, SuperAND
- Removable Flash Card component + controller
 - Create new form factor, faster, secure, smaller
- Hybrid Drive or Robson intermediate sub-system support
 - Shift caching, fetching, bootup, system reliability, application acceleration functions to HDD
- Solid State Drives
 - Complement not compete with HDD
 - Faster, smaller, ruggedized than HDD
- HDD
 - Reduce form factor, increase capacity

How much does developing new technology or sub-systems really benefit the user?

Conclusions

INFLECTION POINT drivers: markets, applications

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Contact: www.web-feetresearch.com





Thank You